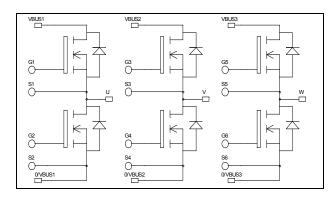


Triple phase leg MOSFET Power Module



$$\begin{split} V_{DSS} &= 200V \\ R_{DSon} &= 16 m \Omega \text{ typ @ Tj} = 25^{\circ} C \\ I_D &= 104 A \text{ @ Tc} = 25^{\circ} C \end{split}$$

Application

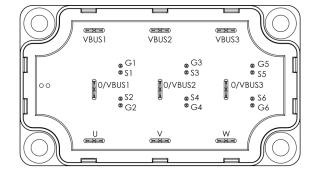
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
 - Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a phase leg of three times the current capability
- Module can be configured as a three phase bridge
- Module can be configured as a boost followed by a full bridge
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V
T	Continuous Drain Current	$T_c = 25^{\circ}C$	104	
I_{D}		$T_c = 80$ °C	77	A
I_{DM}	Pulsed Drain current		416	
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		19	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	390	W
I_{AR}	Avalanche current (repetitive and non repetitive)		104	A
E _{AR}	Repetitive Avalanche Energy		50	ma I
E_{AS}	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			250	μА
		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			1000	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 52A$		16	19	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2.5 \text{mA}$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		7220		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		2330		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		146		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		140		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 100 \text{V}$		53		nC
$Q_{gd} \\$	Gate – Drain Charge	$I_D=104A$		67		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		
T_{r}	Rise Time	$\begin{aligned} &V_{GS} = 15V \\ &V_{Bus} = 133V \\ &I_D = 104A \\ &R_G = 5\Omega \end{aligned}$		64		ns
$T_{d(off)}$	Turn-off Delay Time			88		
T_{f}	Fall Time			116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		849		
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 104A, R_G = 5\Omega$		929		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		936		
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 104A, R_G = 5\Omega$		986		μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
T	Continuous Source current		$Tc = 25^{\circ}C$			104	۸	
I_S	(Body diode)		$Tc = 80^{\circ}C$			77	Α	
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -104A$				1.3	V	
dv/dt	Peak Diode Recovery					5	V/ns	
t_{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$			230	ns	
ι _{rr}	Reverse Recovery Time	$I_S = -104A$ $V_R = 133V$	$T_j = 125$ °C			450	113	
Qrr	Reverse Recovery Charge	$di_{S}/dt = 100A/\mu s$	$T_j = 25^{\circ}C$		0.9		μС	
			$T_{j} = 125^{\circ}C$		3.4		μ	

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

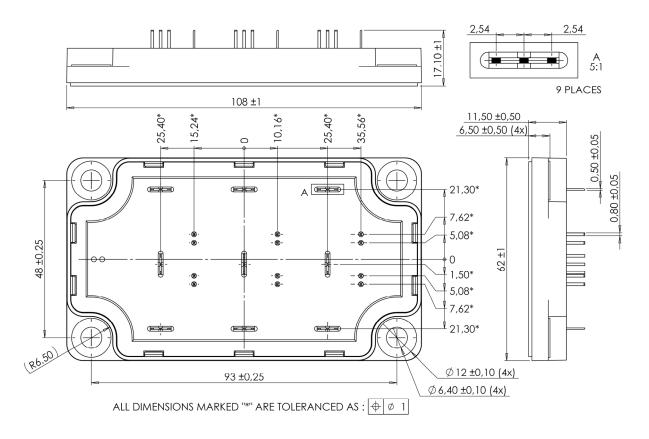
 $I_S \leq \text{--} 104 A \qquad \text{di/dt} \leq 700 A/\mu s \qquad V_R \leq V_{DSS} \qquad T_j \leq 150^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance					0.32	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

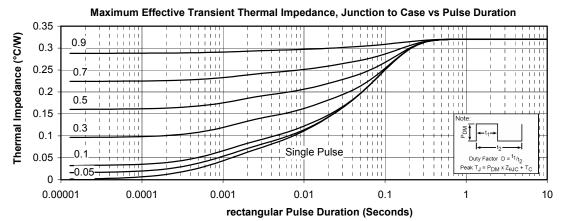
SP6-P Package outline (dimensions in mm)

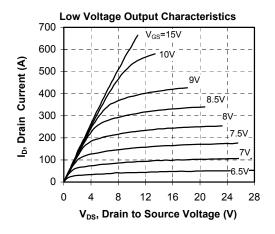


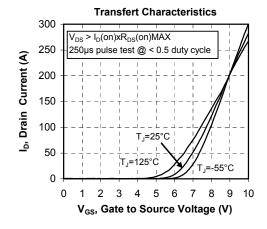
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

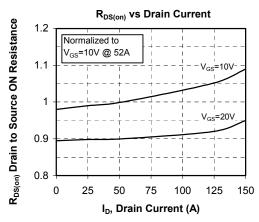


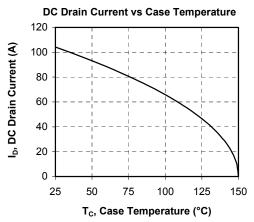
Typical Performance Curve



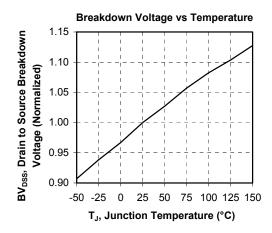


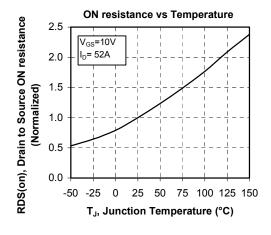


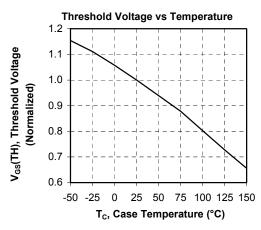


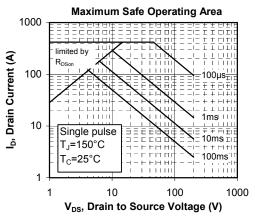


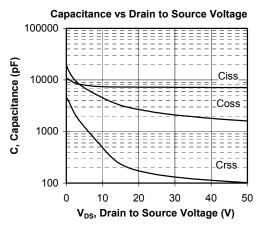


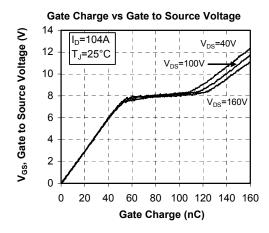




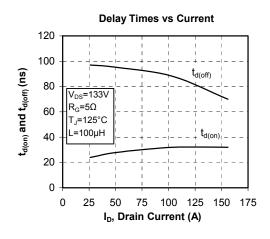


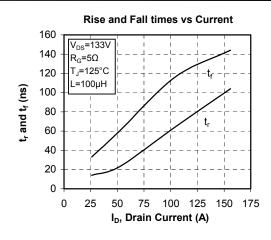


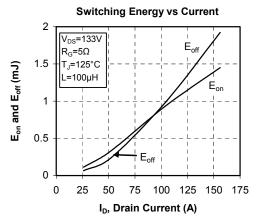


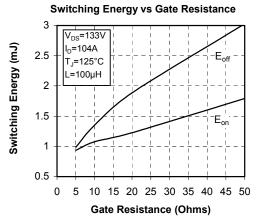


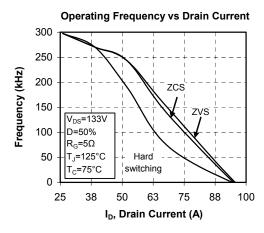


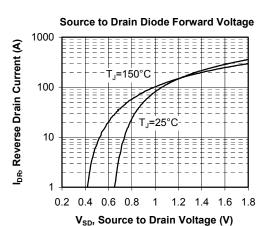














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